



ORIENT

Photo coupler

Product Data Sheet

Part Number: OR-6N137

Customer: _____

Date: _____

SHENZHEN ORIENT COMPONENTS CO., LTD

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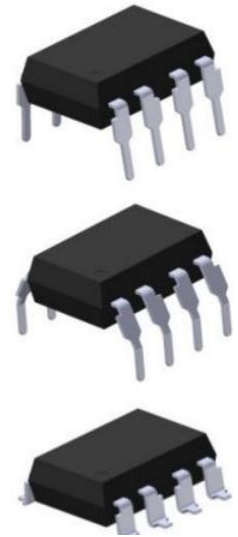
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www.orient-opto.com

Preliminary

This datasheet is a preliminary design specification, and the formal specifications are subject to the recognition letter with jointly signed

1. Features

- (1) 3.3v / 5V supply voltage
- (2) Low power consumption
- (3) High speed: 10MBd
- (4) Open Collector Output
- (5) -40 °C to 105 °C temperature of AC and DC performance.
- (6) Safety approval
 - UL approved (No.E323844)
 - VDE approved (No.4029733)
 - CQC approved (No.CQC19001231254)
- (7) In compliance with RoHS, REACH standards
- (8) MSL Class I



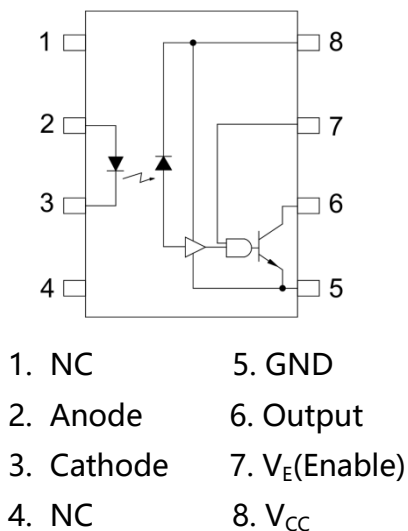
2. Instructions

OR-6N137 is made up of an efficient AlGaAs light-emitting diode and high-speed optical detector. This design provides good ac and dc isolation between the input and output ends of the photoelectric coupler. The output characteristic of the photodetector is a collector open circuit schottky clamp transistor. The photoelectric couple operating temperature range: -40 °C to 105 °C.

3. Application Range

1. line receiver isolation
2. A/ D, D/A converted digital signal isolation
3. eliminate noise from the ground loop
4. switching power supply
5. alternative pulse transformers
6. motor control system
7. interface of microprocessor system, computer and peripheral equipment

4. Functional Diagram



Truth table

Input (LED)	Enable	Output
ON	H	L
OFF	H	H
ON	L	H
OFF	L	H
ON	NC	L
OFF	NC	H

0.1 capacitor F bypass capacitance needs to be connected between A Pin8 and Pin5

5. SAFETY AND INSULATION RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	TEST CONDITION
Climatic classification		55 / 115 / 21		According to DIN EN 60747-5-5
Pollution degree		2		According to DIN EN 60747-5-5
Comparative tracking index	C _{TI}	175		Insulation group IIIa
Maximum rated withstanding isolation voltage	V _{ISO}	5000	V _{RMS}	According to UL1577, t = 1 min
Maximum transient isolation voltage	V _{IOTM}	8000	V _{peak}	According to DIN EN 60747-5-5
Maximum repetitive peak isolation voltage	V _{IORM}	500	V _{peak}	According to DIN EN 60747-5-5
Maximum wave isolation voltage	V _{IOWM}	6000	V _{peak}	According to DIN EN 60747-5-5
Maximum surge isolation voltage	V _{IOSM}	6250	V _{peak}	According to DIN EN 60747-5-5
Isolation resistance	R _{IO}	10 ¹²	Ω	T _{amb} = 25 °C, V _{IO} = 500 V
	R _{IO}	10 ¹¹	Ω	T _{amb} = 100 °C, V _{IO} = 500 V
Creepage distance		8	mm	DIP-8
Clearance distance		8	mm	
Creepage distance		8	mm	DIP-8 (M type)
Clearance distance		8	mm	
Creepage distance		8	mm	SOP-8
Clearance distance		8	mm	
Insulation thickness	DTI	0.5	mm	

6. Absolute Maximum Ratings (Ta=25°C)*1

Parameter		Symbol	Rated Value	Unit
Input	Average Forward Input Current	I _F	20	mA
	Reverse Input Voltage	V _R	5	V
	Power Dissipation	P _I	40	mW
	Enable Input Voltage	V _E	5.5	V
	Enable Input current	I _E	5	mA
Output	Output Collector Current	I _O	50	mA
	Output Collector Voltage	V _O	7	V
	Output Collector Power Dissipation	P _O	85	mW
	Supply Voltage	V _{CC}	7	V
Insulation Voltage		V _{iso}	5000	V _{rms}
Operating Temperature		T _{opr}	-40 ~ + 105	°C
Storage Temperature		T _{stg}	-55 ~ + 125	
*2	Soldering Temperature	T _{sol}	260	

*1. Room temperature = 25 °C. Exceeding the maximum absolute rating can permanently damage the device.

Working long hours at the maximum absolute rating can affect reliability.

*2. soldering time is 10 seconds.

7. Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Operating Temperature	T _A	-40	105	°C
Supply Voltage	V _{CC}	2.7	3.6	V
		4.5	5.5	
Low Level Input Current	I _{FL}	0	250	μA
High Level Input Current	I _{FH}	5	15	mA
Low Level Enable Voltage	V _{EL}	0	0.8	V
High Level Enable Voltage	V _{EH}	2	V _{CC}	V
Fan Out (at R _L =1kΩ per channel)	N	—	5	TTL Loads

8. Opto-electronic Characteristics

	Parameter	Symbol	Min	Typ	Max	Unit	Condition
Input	Forward Voltage	V_F	—	1.39	1.8	V	$I_F = 10\text{mA}$
	Temperature Coefficient OF Forward Voltage	$\Delta V_F / \Delta T$	—	-0.9	—	mV/°C	$I_F = 10\text{mA}$
	Reverse Voltage	BV_R	5	—	—	V	$I_R = 10\mu\text{A}$
	Input Threshold Current	I_{TH}	—	3.3	5	mA	$V_E = 2\text{V}, V_{CC} = 3.3\text{V}$ $V_O = 0.6\text{V}$ $I_{OL} \text{ (sinking)} = 13\text{mA}$
	Input Capacitance	C_{IN}	—	33	—	pF	$f = 1\text{MHz}, V_F = 0\text{V}$
Detector	High Level Supply Current	I_{CCH}	—	5.1	10	mA	$V_E = 0.5\text{V},$ $V_{CC} = 3.3\text{V}, I_F = 0\text{mA}$
	Low Level Supply Current	I_{CCL}	—	7.3	13	mA	$V_E = 0.5\text{V},$ $V_{CC} = 3.3\text{V}, I_F = 10\text{mA}$
	High Level Enable Current	I_{EH}	—	—	-1.6	mA	$V_{CC} = 3.3\text{V}, V_E = 2\text{V}$
	Low Level Enable Current	I_{EL}	—	—	-1.6	mA	$V_{CC} = 3.3\text{V}, V_E = 0.5\text{V}$
	High Level Enable Voltage	V_{EH}	2	—	—	V	
	Low Level Enable Voltage	V_{EL}	—	—	0.8	V	
	High Level Output Current	I_{OH}	—	8.5	100	μA	$V_E = 2\text{V}, V_{CC} = 3.3\text{V},$ $V_O = 3.2\text{V}, I_F = 250\mu\text{A}$
	Low Level Output Voltage	V_{OL}	—	0.43	0.6	V	$V_E = 2\text{V}, V_{CC} = 3.3\text{V},$ $I_F = 5\text{mA},$ $I_{OL} \text{ (sinking)} = 13\text{mA}$

Typical values $T_A = 25^\circ\text{C}, V_{CC} = 3.3\text{V}$.

Parameter		Symbol	Min	Typ	Max	Unit	Condition
Input	Forward Voltage	V_F	—	1.39	1.8	V	$I_F = 10\text{mA}$
	Temperature Coefficient OF Forward Voltage	$\Delta V_F / \Delta T$	—	-0.9	—	mV/°C	$I_F = 10\text{mA}$
	Reverse Voltage	BV_R	5	—	—	V	$I_R = 10\mu\text{A}$
	Input Threshold Current	I_{TH}	—	3.5	5	mA	$V_{CC}=5.5\text{V}, V_O=0.6\text{V}$ $I_{OL}>13\text{mA}$
	Input Capacitance	C_{IN}	—	33	—	pF	$f = 1\text{MHz}, V_F = 0\text{V}$
Detector	High Level Supply Current	I_{CCH}	—	7.6	10	mA	$V_E = 0.5\text{V},$ $V_{CC}=5.5\text{V}, I_F=0\text{mA}$
	Low Level Supply Current	I_{CCL}	—	9.8	13	mA	$V_E = 0.5\text{V},$ $V_{CC}= 5.5\text{V}, I_F=10\text{mA}$
	High Level Enable Current	I_{EH}	—	—	-1.6	mA	$V_{CC}= 5.5\text{V}, V_E=2\text{V}$
	Low Level Enable Current	I_{EL}	—	—	-1.6	mA	$V_{CC}= 5.5\text{V}, V_E=0.5\text{V}$
	High Level Enable Voltage	V_{EH}	2	—	—	V	
	Low Level Enable Voltage	V_{EL}	—	—	0.8	V	
	High Level Output Current	I_{OH}	—	4.5	100	μA	$V_E=2\text{V}, V_{CC}=5.5\text{V},$ $V_O=5.5\text{V}, I_F=250\mu\text{A}$
	Low Level Output Voltage	V_{OL}	—	0.43	0.6	V	$V_E=2\text{V}, V_{CC}=5.5\text{V},$ $I_F=5\text{mA},$ $I_{OL}(\text{sinking}) = 13\text{mA}$

Typical values $T_A = 25^\circ\text{C}$.

9. Switching Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Propagation delay time to output High level	t_{PLH}	—	48	90	ns	$R_L=350\Omega, C_L=15pF$
Propagation delay time to output Low level	t_{PHL}	—	35	75	ns	
Pulse Width Distortion	$ t_{PLH}-t_{PHL} $	—	13	—	ns	
Output Rise Time (10 to 90%)	t_r	—	21	—	ns	
Output Fall Time (90 to 10%)	t_f	—	6.6	—	ns	
Propagation Delay Time of Enable from V_{EH} to V_{EL}	t_{ELH}	—	27	—	ns	$R_L=350\Omega, C_L=15pF$ $V_{EL}=0V, V_{EH}=3V$
Propagation Delay Time of Enable from V_{EL} to V_{EH}	t_{EHL}	—	9	—	ns	

Operating temperature range ($T_A = -40^\circ C$ to $105^\circ C$, $2.7V \leq V_{CC} \leq 3.6V$), $I_F = 7.5mA$ Unless otherwise stated.

Typical values $T_A = 25^\circ C, V_{CC} = 3.3V$.

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Propagation delay time to output High Level	t_{PLH}	—	40	75	ns	$R_L=350\Omega, C_L=15pF$
Propagation delay time to output Low Level	t_{PHL}	—	32	75	ns	
Pulse Width Distortion	$ t_{PLH}-t_{PHL} $	—	8	—	ns	
Output Rise Time (10 to 90%)	t_r	—	22	—	ns	
Output Fall Time (90 to 10%)	t_f	—	6.9	—	ns	
Propagation Delay Time of Enable from V_{EH} to V_{EL}	t_{ELH}	—	28	—	ns	$R_L=350\Omega, C_L=15pF$ $V_{EL}=0V, V_{EH}=3V$
Propagation Delay Time of Enable from V_{EL} to V_{EH}	t_{EHL}	—	12	—	ns	

Operating temperature range ($T_A = -40^\circ C$ to $105^\circ C$, $4.5V \leq V_{CC} \leq 5.5V$), $I_F = 7.5mA$ Unless otherwise stated.

Typical values $T_A = 25^\circ C, V_{CC} = 5.0V$.

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Input-Output Insulation Leakage Current	I _{I-O}	—	—	1	μA	45% RH, t=5s, V _{I-O} = 3KV DC, T _A =25 C
Withstand Insulation Test Voltage	V _{ISO}	5000	—	—	V _{RMS}	RH ≤ 50%, t =1min, T _A =25°C
Input-Output Resistance	R _{I-O}	—	10 ¹²	—	Ω	V _{I-O} =500V DC
Input-Output Capacitance	C _{I-O}	—	1		p	f = 1MHz, T _A = 25 C

Typical values T_A = 25°C.

10. Order Information

Part Number

OR-6N137Y-Z

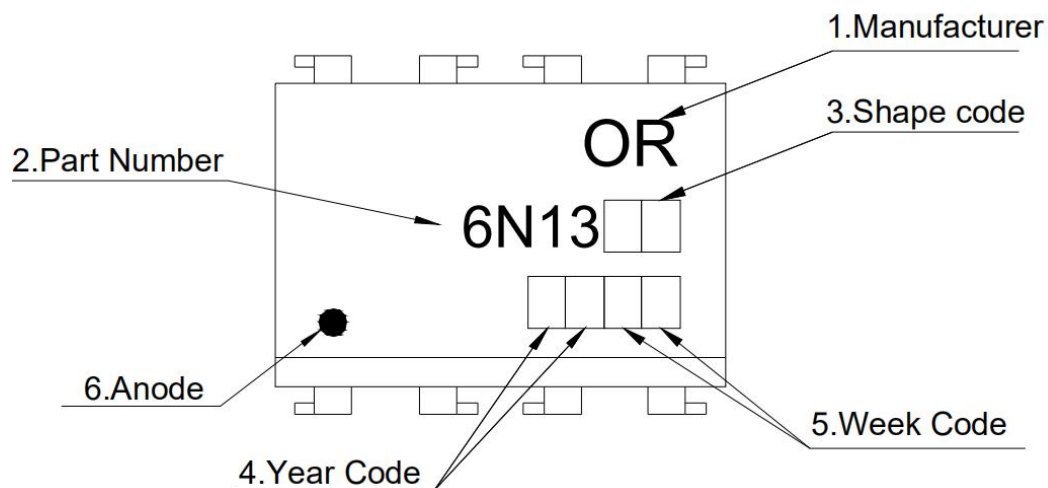
Note

Y = Lead form option (S, M or none)

Z = Tape and reel option (TA,TA1 or none).

Option	Description	Packing quantity
None	Standard SMD Option	45 units per tube
M	Wide lead bend (0.4 inch spacing)	45 units per tube
TA	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
TA1	Surface mount lead form (low profile) + TA1 tape & reel option	1000 units per reel

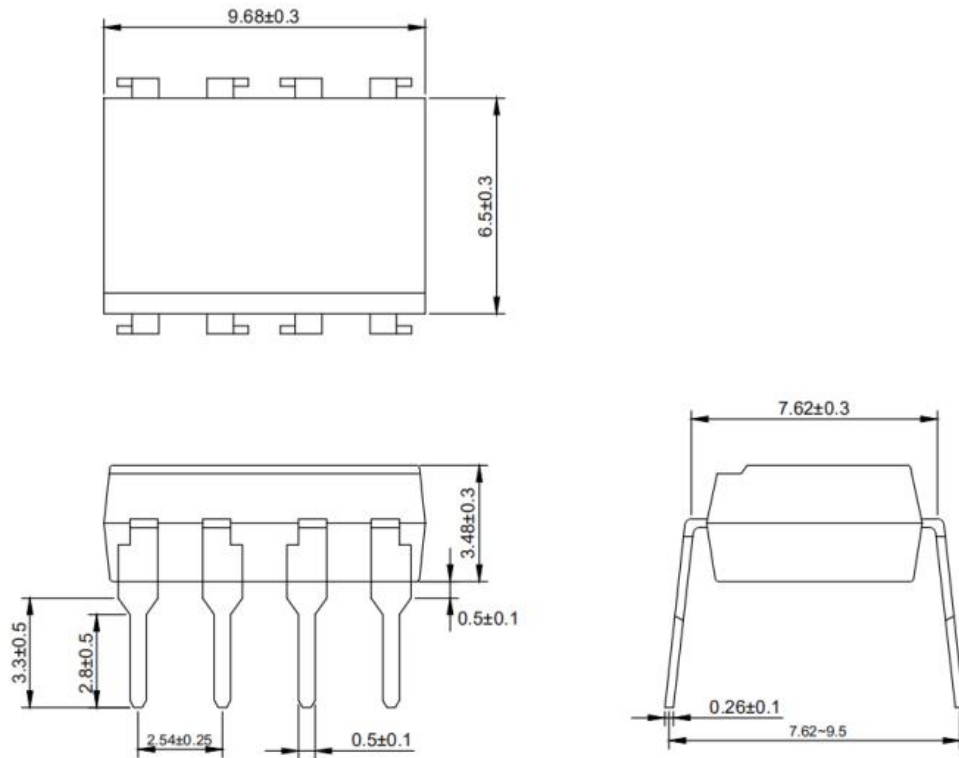
11. Naming Rule



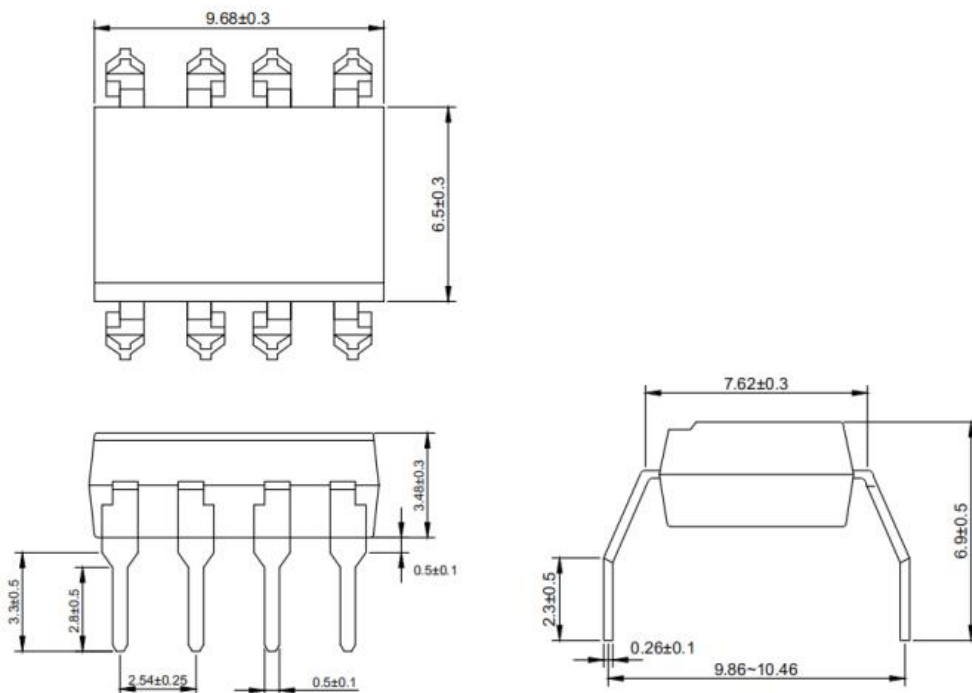
1. Manufacturer : ORIENT.
2. Part Number : 6N137.
3. Shape Code .
4. Year Code : '21' means '2021' and so on.
5. Week Code : 01 means the first week, 02 means the second week and so on.
6. Anode.

12. Outer Dimension

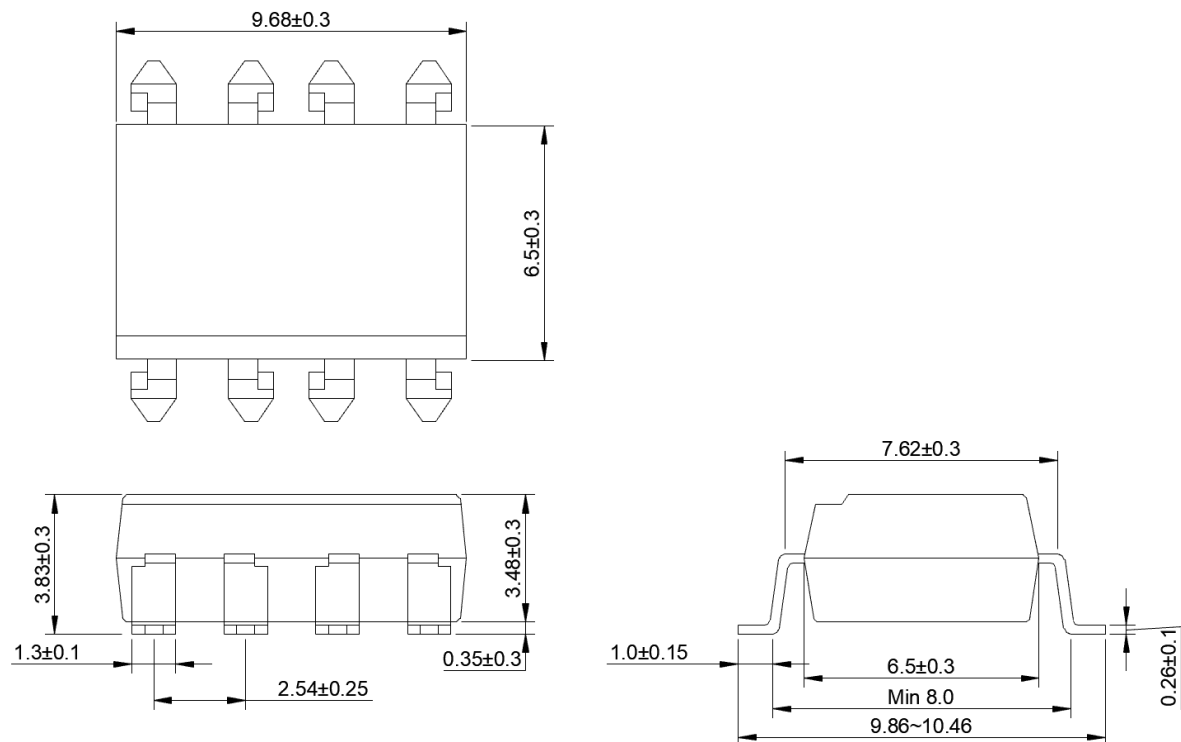
(1) OR-6N137



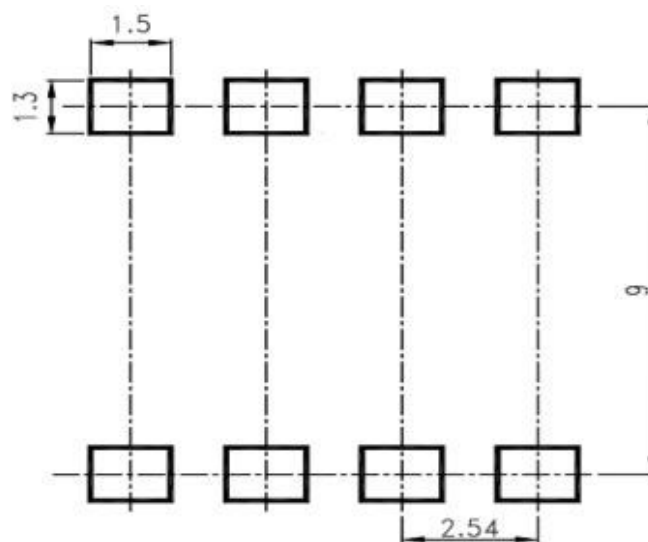
(2) OR-6N137M



(3) OR-6N137S



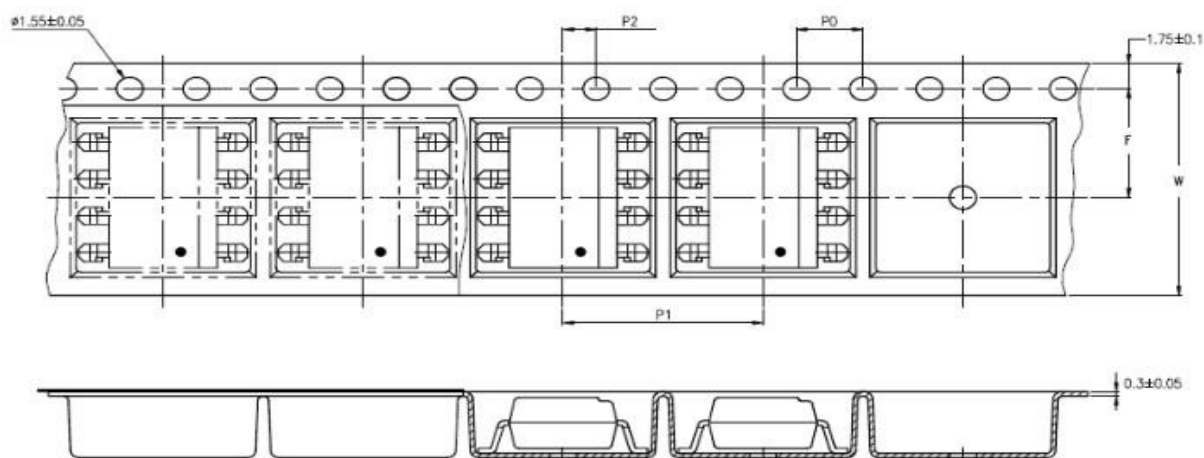
12、 Recommended Foot Print Patterns (Mount Pad)



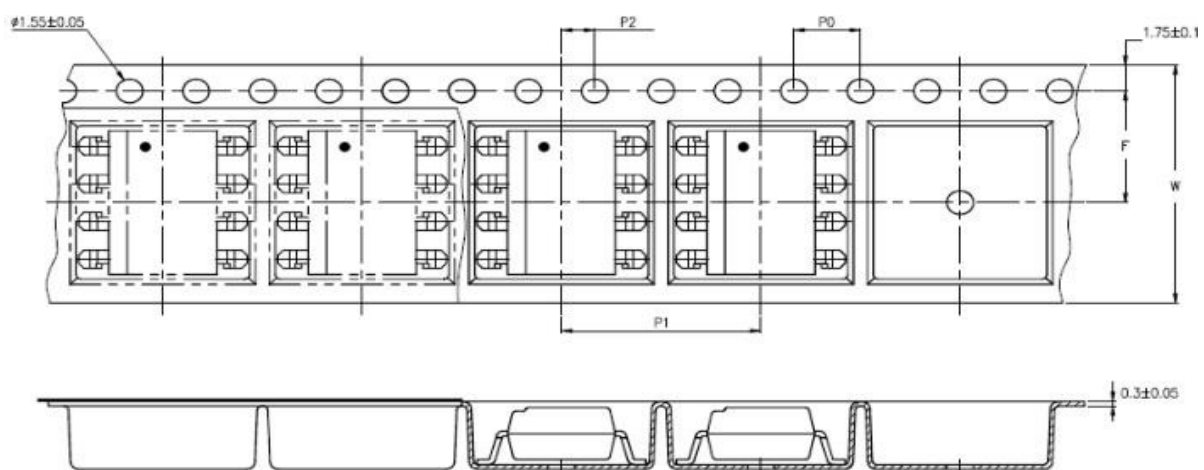
unit: mm

13. Taping Dimensions

(1) OR-6N137S-TA



(2) OR-6N137S-TA1



type	symbol	Size: mm (inches)
bandwidth	W	16 ± 0.3 (0.63)
pitch	P_0	4 ± 0.1 (0.15)
pitch	F	7.5 ± 0.1 (0.295)
	P_2	2 ± 0.1 (0.079)
interval	P_1	12 ± 0.1 (0.472)

Encapsulation type	TA/TA1
amount (pcs)	1000

14. Package Dimension

(1) package dimension

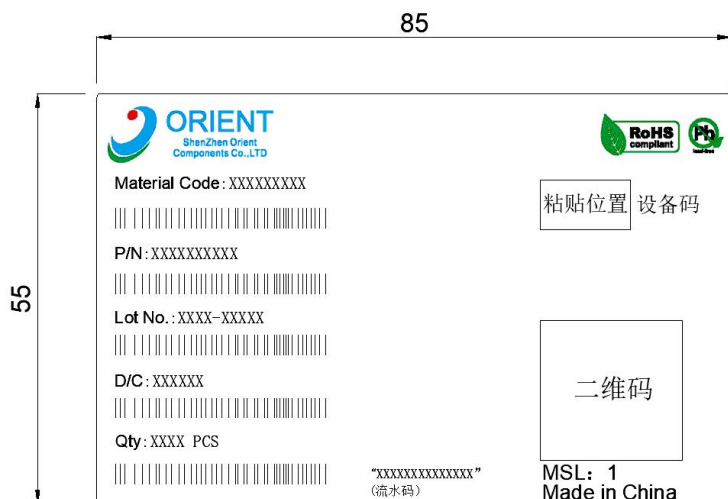
DIP Type

Packing Information	
Packing type	Tube
Qty per Tube	45pcs
Small box (Inner) Dimension	525*128*60mm
Large box (Outer) Dimension	545*290*335mm
The Amount per Inner Box	2,250pcs
The Amount per Outer Box	22,500pcs

SOP Type

Packing Information	
Packing type	Reel type
Tape Width	16mm
Qty per Reel	1,000pcs
Small box (inner) Dimension	345*345*58.5mm
Large box (Outer) Dimension	620x360x360mm
Max qty per small box	2,000pcs
Max qty per large box	20,000pcs

(2)Packing Label Sample



Note:

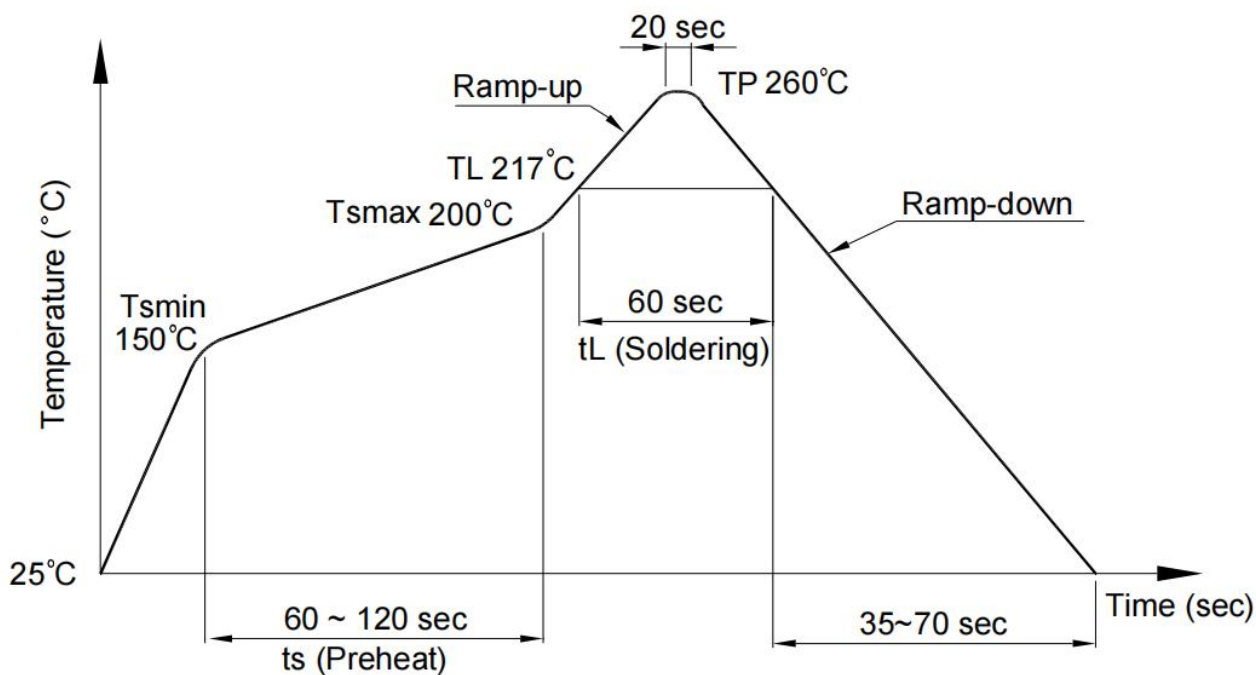
1. Material Code :Product ID.
2. P/N :Contents with "Order Information" in the specification.
3. Lot No. :Product weeks.
4. D/C :Product data.
5. Quantity :Packaging quantity.

15. Temperature Profile Of Soldering

(1) IR Reflow soldering (JEDEC-STD-020 compliant)

Note: one solder backflow is recommended under the conditions described below in the temperature and time profile. Do not weld more than three times.

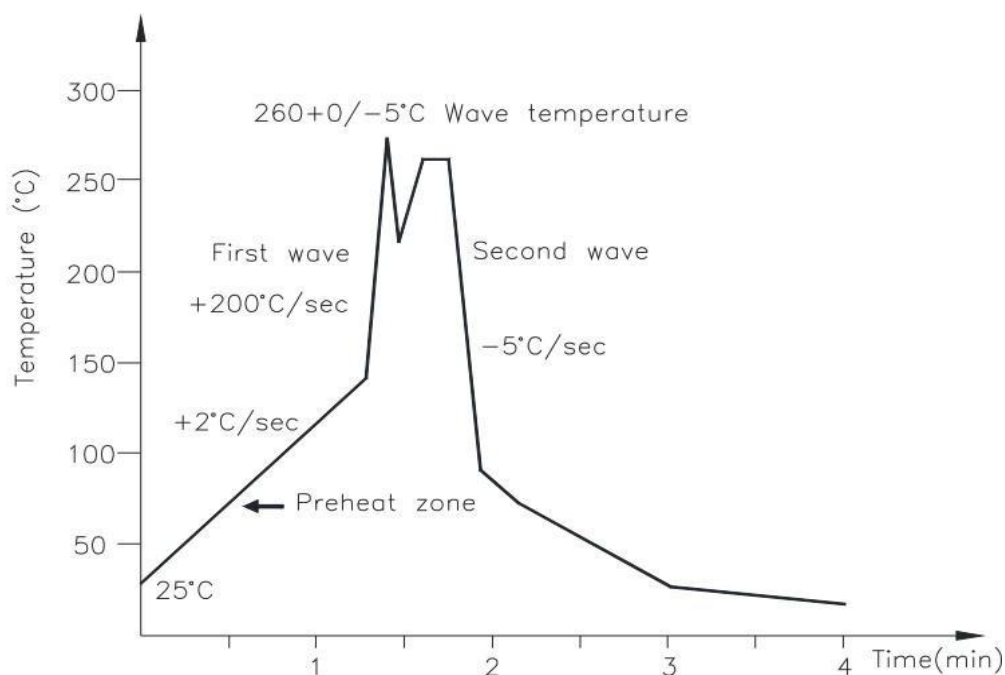
Profile item	Conditions
Preheat	
- Temperature Min (T Smin)	150°C
- Temperature Max (T Smax)	200°C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (TL)	217°C
- Time (t L)	60 sec
Peak Temperature	260°C
Peak Temperature time	20 sec
Ramp-up rate	3°C / sec max.
Ramp-down rate from peak temperature	3~6°C / sec
Reflow times	≤3



(2) Wave soldering (JEDEC22A111 compliant)

One-time welding is recommended under the temperature condition.

Temperature	260+0/-5°C
Time	10 sec
Preheat temperature	5 to 140°C
Preheat time	30 to 80 sec



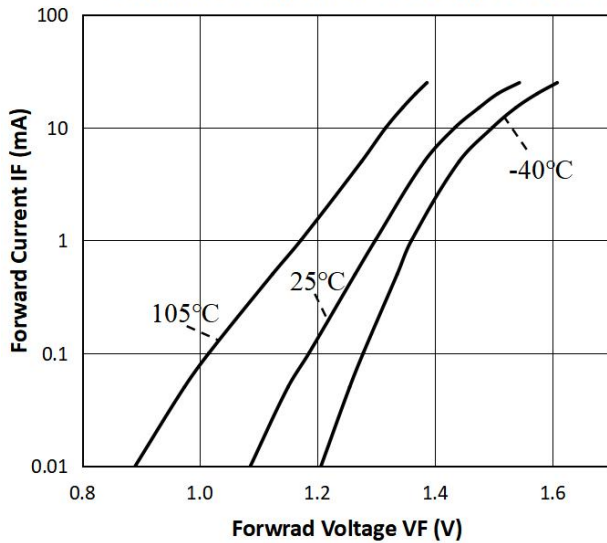
(3) Hand soldering by soldering iron

Single lead welding is allowed in each process and one-time welding is recommended.

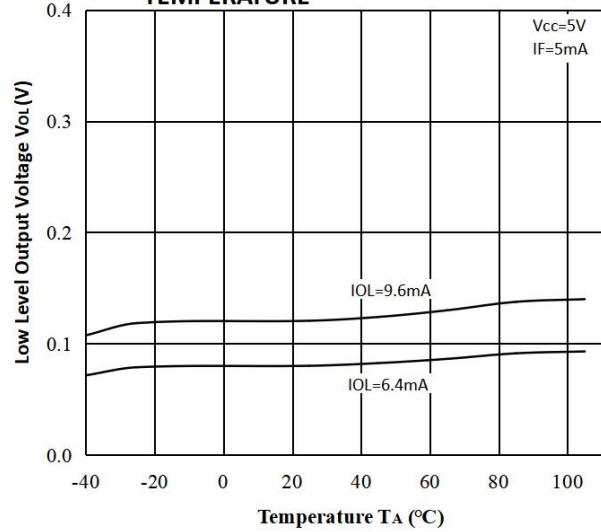
Temperature	380+0/-5°C
Time	3 sec max

16. Characteristics Curve

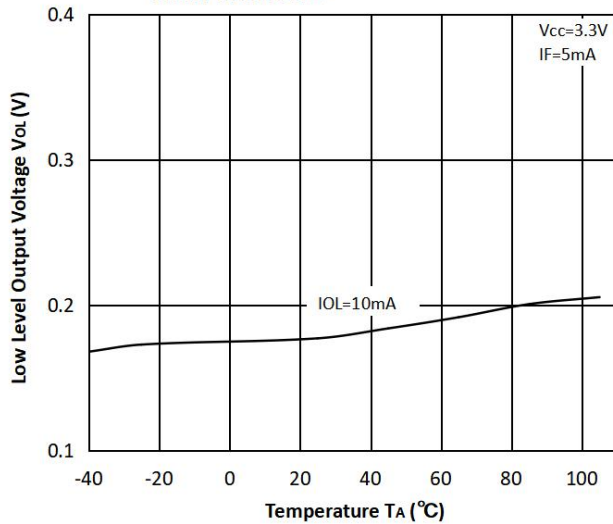
FORWARD CURRENT vs. FORWARD VOLTAGE



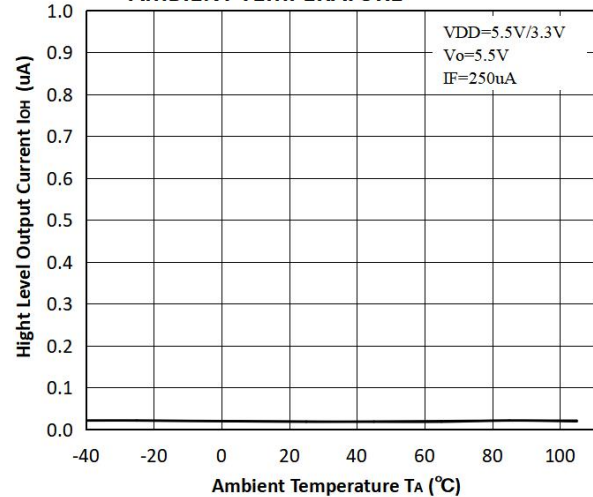
LOW LEVEL OUTPUT VOLTAGE vs. TEMPERATURE



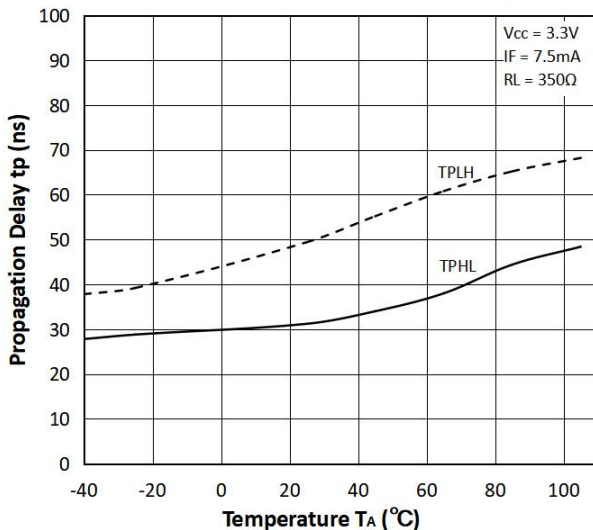
LOW LEVEL OUTPUT VOLTAGE vs. TEMPERATURE



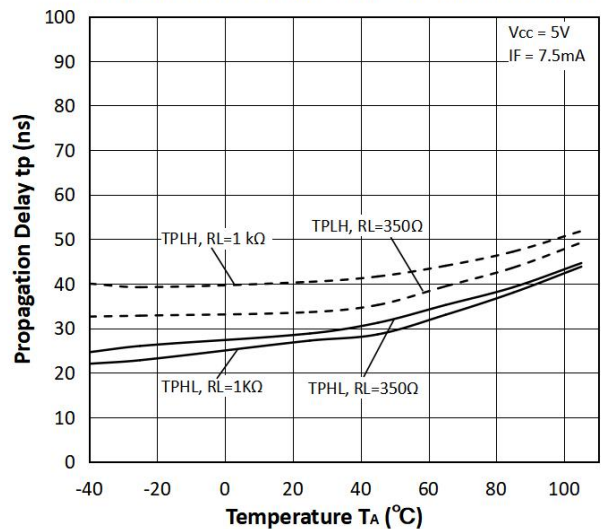
HIGHT LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME vs. TEMPERATURE



PROPAGATION DELAY TIME vs. TEMPERATURE



17. Switching time test circuit

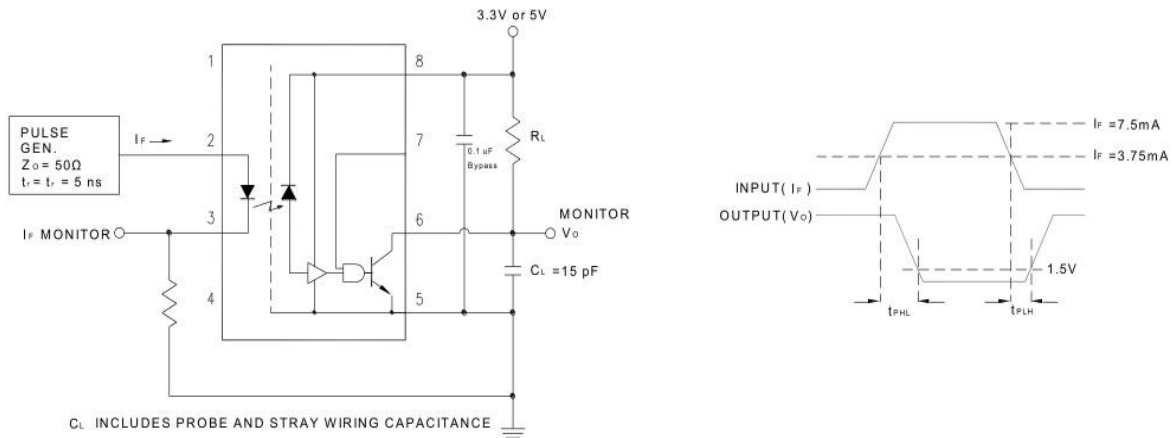


Figure 1: Test Circuit for t_{PHL} and t_{PLH}

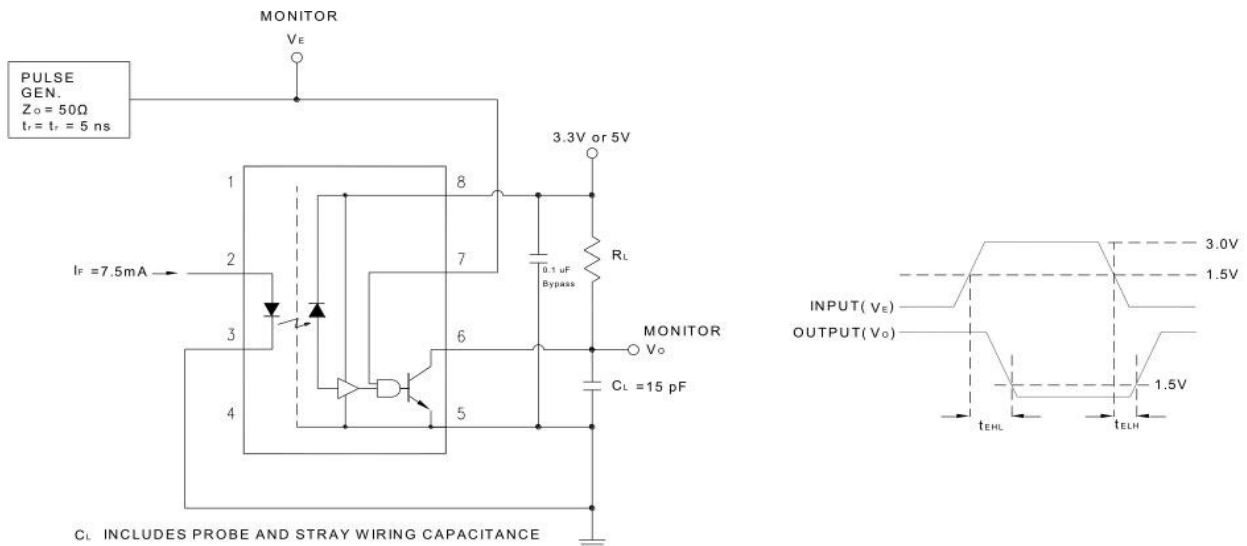


Figure 2: Single Channel Test Circuit for Common Mode Transient Immunity

18. NOTES

- (1) Orient is continually improving the quality, reliability, function or design and Orient reserves the right to make changes without further notices.
- (2) The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- (3) For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- (4) When requiring a device for any “specific” application, please contact our sales in advice.
- (5) If there are any questions about the contents of this publication, please contact us at your convenience.
- (6) The contents described herein are subject to change without prior notice.
- (7) Immerge unit’s body in solder paste is not recommended.